

### 2ch High Side Switch ICs

# **Current Limit High Side Switch ICs**

### BD6516F BD6517F BD2042AFJ BD2052AFJ

#### **General Description**

BD6516F, BD6517F, BD2042AFJ and BD2052AFJ are dual channel high side switch ICs with an over current protection for Universal Serial Bus (USB) power supply line. The IC's switch unit has two channels of N-Channel power MOSFET. Over current detection circuit, thermal shutdown circuit, under voltage lockout and soft start circuit are built in.

#### **Features**

- Dual N-MOS High Side Switch
- Control Input Logic
  - Active-Low: BD6517F, BD2042AFJ
     Active-High: BD6516F, BD2052AFJ
- Soft Start Circuit
- Over Current Detection
- Thermal Shutdown
- Under Voltage Lockout
- Open Drain Error Flag Output
- Reverse-Current Protection when Switch Off
- Flag Output Delay

#### **Applications**

USB Hub in Consumer Appliances, Note PC, PC Peripheral Equipment, and so on.

#### **Typical Application Circuit**

### **Key Specifications**

■ Input Voltage Range:

BD6516F/BD6517F 3.0V to 5.5V

BD2042AFJ/BD2052AFJ 2.7V to 5.5V

■ ON-Resistance:

BD6516F/BD6517F  $110m\Omega(Typ)$ BD2042AFJ/BD2052AFJ  $100m\Omega(Typ)$ Continuous Current: 0.5A

Current Limit Threshold:

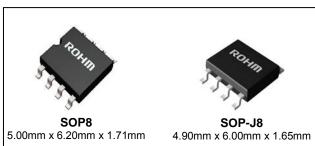
BD6516F/BD6517F 1.2A(Min), 2.5A (Max) BD2042AFJ/BD2052AFJ 0.7A(Min), 1.8A (Max)

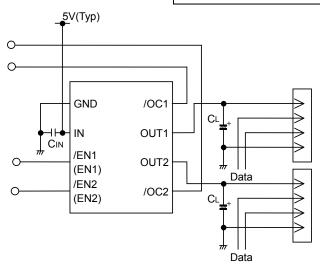
■ Standby Current: 0.01µA (Typ)
■ Output Rise Time: 1.8ms (Typ)

Operating Temperature Range:

BD6516F/BD6517F -25°C to +85°C BD2042AFJ/BD2052AFJ -40°C to +85°C

### Packages W(Typ) D(Typ) H(Max)



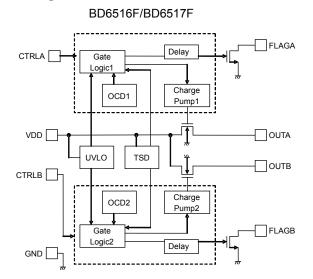


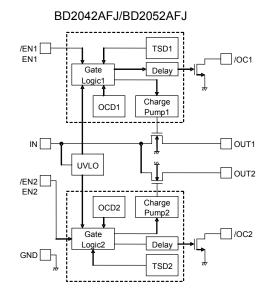
#### Lineup

Curr	Current Limit Threshold		Control Innut Logic	Dealtons		Orderable Part Number
Min	Тур	Max	Control Input Logic	F	ackage	Orderable Part Number
1.2A	1.65A	2.5A	High	CODO		BD6516F-E2
1.2A	1.65A	2.5A	Low	SOP8	Daal of 2500	BD6517F-E2
0.7A	1.0A	1.8A	High	COD 10	Reel of 2500	BD2052AFJ-E2
0.7A	1.0A	1.8A	Low	SOP-J8		BD2042AFJ-E2

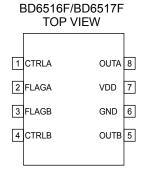
OProduct structure: Silicon monolithic integrated circuit OThis product has not designed protection against radioactive rays

### **Block Diagrams**

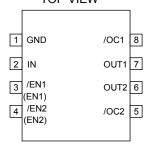




### **Pin Configurations**



### BD2042AFJ/BD2052AFJ TOP VIEW



### **Pin Descriptions**

BD6516F/BD6517F

	6F/BD6517F		T
Pin No.	Symbol	1/0	Pin Function
1, 4	CTRLA CTRLB	I	Enable input. Switch on at low level. (BD6517F) Low level input < 0.7V. Switch on at high level. (BD6516F) High level input > 2.5V.
2, 3	FLAGA FLAGB	0	Error flag output. Low at over current, thermal shutdown. Open drain output.
5, 8	OUTA OUTB	0	Switch output.
6	GND	I	Ground.
7	VDD	ı	Power supply input. Input terminal of the switch and power supply of internal circuit.

#### BD2042AFJ/BD2052AFJ

Pin No.	Symbol	1/0	Pin Function
1	GND	I	Ground.
2	IN	I	Power supply input. Input terminal of the switch and power supply of internal circuit.
3, 4	/EN1 /EN2, EN1 EN2	I	Enable input. /EN: Switch on at low level. (BD2042AFJ) Low level input < 0.8V EN: Switch on at high level. (BD2052AFJ) High level input > 2.0V.
5, 8	/OC2 /OC1	0	Error flag output. Low at over current, thermal shutdown. Open drain output.
6, 7	OUT2 OUT1	0	Switch output.

### **Absolute Maximum Ratings**

BD6516F/BD6517F

Parameter	Symbol	Rating	Unit
Input Voltage	VDD	-0.3 to +6.0	V
CTRL Voltage	Vctrl	-0.3 to V <sub>DD</sub> +0.3	V
FLAG Voltage	VFLAG	-0.3 to +6.0	V
Output Voltage	Vout	-0.3 to +6.0	V
Storage Temperature	Tstg	-55 to +150	°C
Power Dissipation	Pd	0.67 <sup>(Note 1)</sup>	W

#### BD2042AFJ/BD2052AFJ

DDZO1Z/(I O/DDZOOZ/(I O			
Parameter	Symbol	Rating	Unit
Input Voltage	VIN	-0.3 to +6.0	٧
EN, /EN Voltage	VEN, V/EN	-0.3 to +6.0	V
/OC Voltage	V/oc	-0.3 to +6.0	V
/OC Current	Is/oc	10	mA
OUT Voltage	Vout	-0.3 to +6.0	V
Storage Temperature	Tstg	-55 to +150	°C
Power Dissipation	Pd	0.67 <sup>(Note 1)</sup>	W

(Note 1) Mounted on 70mm x 70mm x 1.6mm glass-epoxy PCB. Derating : 5.4mW/°C above Ta=25 °C

Caution: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

### **Recommended Operation Conditions**

BD6516F/BD6517F

Parameter	Symbol	Symbol				
Farameter	Symbol Min		Тур	Max	Unit	
Input Voltage	$V_{DD}$	3.0	-	5.5	V	
Operation Temperature	Topr	-25	-	+85	°C	
Continuous Output Current	I <sub>LO</sub>	0	-	500	mA	

### BD2042AFJ/BD2052AFJ

B	0		Rating			
Parameter	Symbol	Min	Min Typ Max			
Input Voltage	V <sub>IN</sub>	2.7	-	5.5	V	
Operation Temperature	Topr	-40	-	+85	°C	
Continuous Output Current	I <sub>LO</sub>	0	-	500	mA	

### **Electrical Characteristics**

BD6516F/BD6517F (V<sub>DD</sub>=5V, Ta=25 °C, unless otherwise specified.)

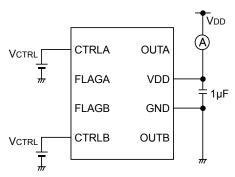
Parameter	Symbol		Limit		Unit	Conditions
Farameter	Symbol	Min	Тур	Max	Offic	
Operating Current	I <sub>DD</sub>	ı	100	140	μΑ	V <sub>CTRL</sub> =5V(BD6516F), 0V(BD6517F) OUT=OPEN
Standby Current	I <sub>STB</sub>	-	0.01	2	μΑ	V <sub>CTRL</sub> =0V(BD6516F), 5V(BD6517F) OUT=OPEN
CTRL Input Voltage	V <sub>CTRL</sub>	-	-	0.7	V	Low Level Input Voltage
OTTLE IIIput Voltage	VCIRL	2.5	-	-	V	High Level Input Voltage
CTRL Input Current	I <sub>CTRL</sub>	-1	+0.01	+1	μA	V <sub>CTRL</sub> =0V or 5V
FLAG Output Resistance	$R_{FLAG}$	ı	250	450	Ω	I <sub>FLAG</sub> =1mA
FLAG Output Leak Current	I <sub>FLAG</sub>	-	0.01	1	μA	V <sub>FLAG</sub> =5V
FLAG Output Delay	t/FL	-	1	4	ms	
ON-Resistance	В	-	110	150	mΩ	V <sub>DD</sub> =5V, I <sub>OUT</sub> =500mA
ON-Resistance	R <sub>ON</sub>	-	140	180	mΩ	V <sub>DD</sub> =3.3V, I <sub>OUT</sub> =500mA
Over-Current Threshold	I <sub>TH</sub>	1.2	1.65	2.5	Α	
Short Circuit Output Current	I <sub>sc</sub>	1.2	1.65	2.2	Α	V <sub>OUT</sub> =0V
Output Leak Current	I <sub>LEAK</sub>	-	-	10	μA	V <sub>CTRL</sub> =0V(BD6516F), 5V(BD6517F)
Thermal Shutdown Threshold	T <sub>TS</sub>	-	135	ı	°C	At Tj Increase
Output Rise Time	t <sub>ON1</sub>	0.1	1.3	4.0	ms	$R_L=10\Omega$
Output Turn ON Delay Time	t <sub>ON2</sub>	0.2	1.5	6.0	ms	$R_L$ =10 $\Omega$
Output Fall Time	t <sub>OFF1</sub>	-	1	20	μs	$R_L$ =10 $\Omega$
Output Turn OFF Delay Time	t <sub>OFF2</sub>	-	3	20	μs	R <sub>L</sub> =10Ω

BD2042AFJ/BD2052AFJ ( $V_{DD}$  =5V, Ta=25 °C, unless otherwise specified.)

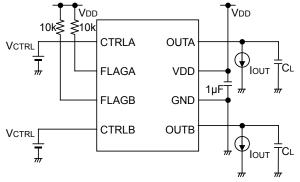
Parameter	Symbol		Limit		Unit	Conditions	
Farameter	Symbol	Min	Тур	Max	Offic	Conditions	
Operating Current	I <sub>DD</sub>	-	110	140	μA	V <sub>/EN</sub> = 0V, OUT = OPEN (BD2042AFJ) V <sub>EN</sub> = 5V, OUT = OPEN (BD2052AFJ)	
Standby Current	I <sub>STB</sub>	-	0.01	1	μA	V <sub>/EN</sub> = 5V, OUT = OPEN (BD2042AFJ) V <sub>EN</sub> = 0V, OUT = OPEN (BD2052AFJ)	
	$V_{/ENH}, \ V_{ENH}$	2.0	-	-	V	High Input	
/EN, EN Input Voltage	V/ENL,	-	-	0.8	V	Low Input	
	V <sub>ENL</sub>	-	-	0.4	V	Low Input 2.7V≤ V <sub>IN</sub> ≤4.5V	
/EN, EN Input Current	I <sub>/EN</sub> , I <sub>EN</sub>	-1.0	+0.01	+1.0	μA	$V_{/EN}$ , $V_{EN}$ = 0V or $V_{/EN}$ , $V_{EN}$ = 5V	
/OC Output Low Voltage	V <sub>/OC</sub>	ı	-	0.5	V	I <sub>/OC</sub> = 5mA	
/OC Output Leak Current	I <sub>L/OC</sub>	-	0.01	1	μΑ	V <sub>/OC</sub> = 5V	
ON-Resistance	Ron	i	100	130	mΩ	I <sub>OUT</sub> = 500mA	
Over-Current Threshold	I <sub>TH</sub>	0.7	1.0	1.8	Α		
Short Circuit Output Current	I <sub>SC</sub>	0.7	1.0	1.3	Α	$V_{IN} = 5V, V_{OUT} = 0V,$ $C_L = 100 \mu F (RMS)$	
Output Rise Time	t <sub>ON1</sub>	ı	1.8	10	ms		
Output Turn ON Time	t <sub>ON2</sub>	-	2.1	20	ms	B - 100 C - OPEN	
Output Fall Time	t <sub>OFF1</sub>	-	1	20	μs	$R_L = 10\Omega$ , $C_L = OPEN$	
Output Turn OFF Time	t <sub>OFF2</sub>	-	3	40	μs		
UVLO Threshold	$V_{TUVH}$	2.1	2.3	2.5	V	Increasing V <sub>IN</sub>	
OVEO TITESTIOIO	$V_{TUVL}$	2.0	2.2	2.4	V	Decreasing V <sub>IN</sub>	

#### **Measurement Circuits**

BD6516F/BD6517F



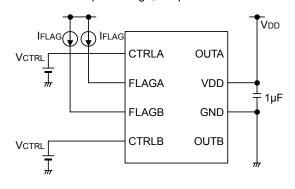
A. Operating Current



C. ON-Resistance, Over Current Detection

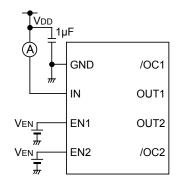
#### 

B. CTRL Input Voltage, Output Rise / Fall Time

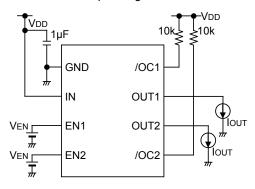


D. FLAG Output Resistance

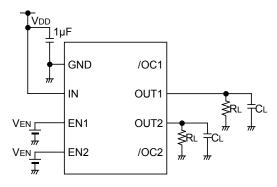
#### BD2042AFJ/BD2052AFJ



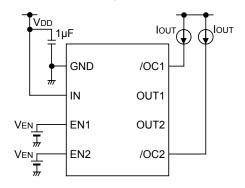
E. Operating Current



G. ON-Resistance, Over Current Detection



F. EN, /EN Input Voltage, Output Rise / Fall Time



H. /OC Output Low Voltage

Figure 1. Measurement Circuits

### **Timing Diagram**

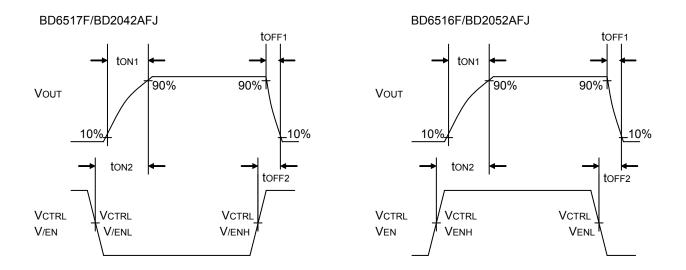


Figure 2. Timing Diagram

### **Typical Performance Curves**

BD6516F/ BD6517F

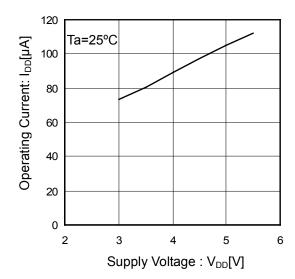


Figure 3. Operating Current vs Supply Voltage

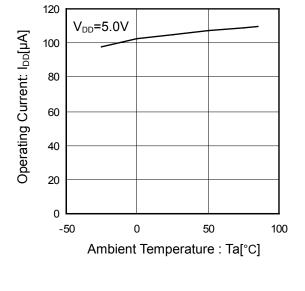


Figure 4. Operating Current vs Ambient Temperature

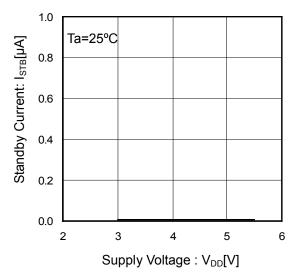


Figure 5. Standby Current vs Supply Voltage

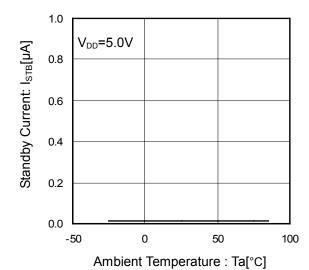


Figure 6. Standby Current vs Ambient Temperature

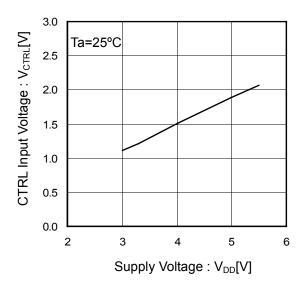


Figure 7. CTRL Input Voltage vs Supply Voltage (BD6516F)

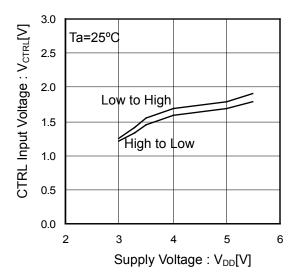


Figure 9. CTRL Input Voltage vs Supply Voltage (BD6517F)

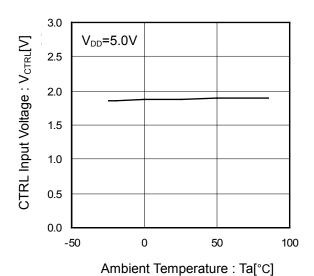


Figure 8. CTRL Input Voltage vs Ambient Temperature (BD6516F)

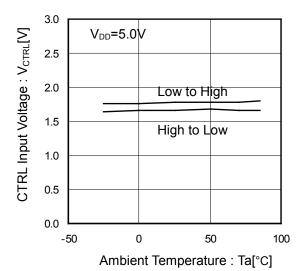


Figure 10. CTRL Input Voltage vs Ambient Temperature (BD6517F)

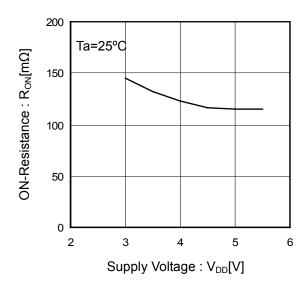


Figure 11. ON-Resistance vs Supply Voltage

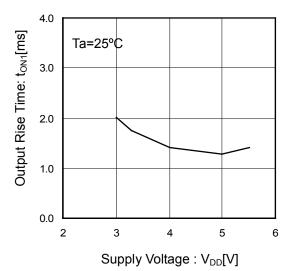


Figure 13. Output Rise Time vs Supply Voltage

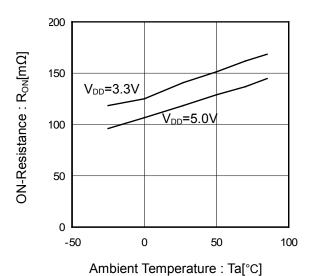


Figure 12. ON-Resistance vs Ambient Temperature

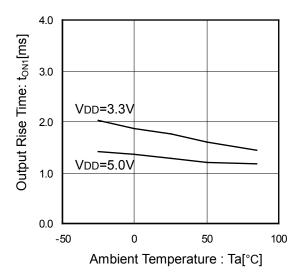


Figure 14. Output Rise Time vs Ambient Temperature

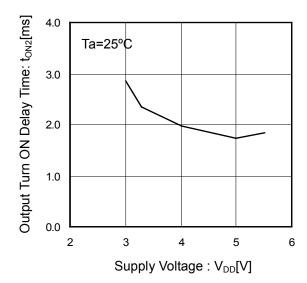


Figure 15. Output Turn ON Delay Time vs Supply Voltage

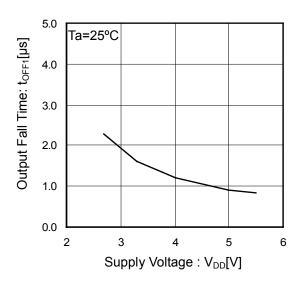


Figure 17. Output Fall Time vs Supply Voltage

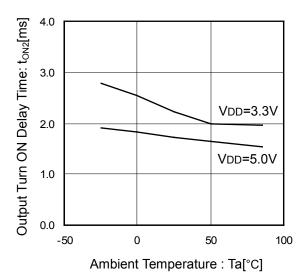


Figure 16. Output Turn ON Delay Time vs Ambient Temperature

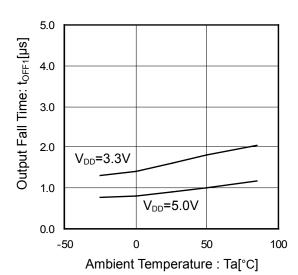


Figure 18. Output Fall Time vs Ambient Temperature

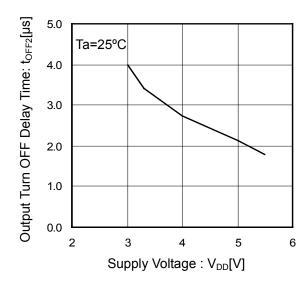


Figure 19. Output Turn OFF Delay Time vs Supply Voltage

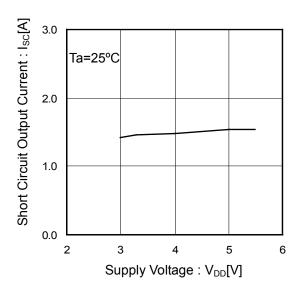


Figure 21. Short Circuit Output Current vs Supply Voltage

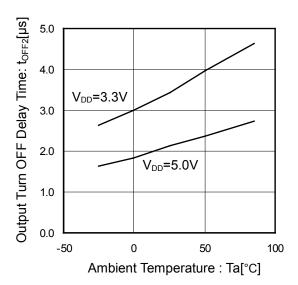


Figure 20. Output Turn OFF Delay Time vs Ambient Temperature

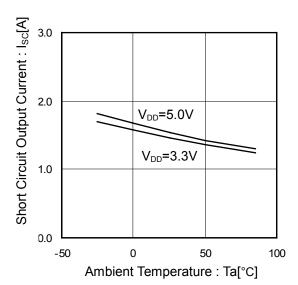


Figure 22. Short Circuit Output Current vs Ambient Temperature

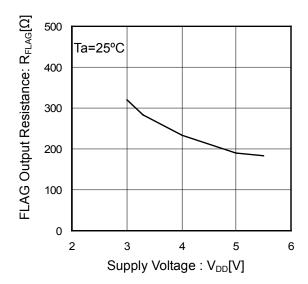


Figure 23. FLAG Output Resistance vs Supply Voltage

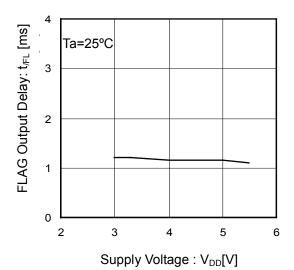


Figure 25. FLAG Output Delay vs Supply Voltage

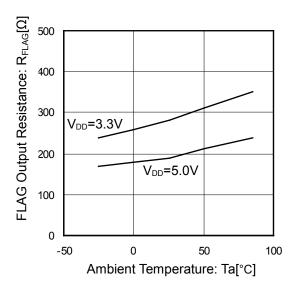


Figure 24. FLAG Output Resistance vs Ambient Temperature

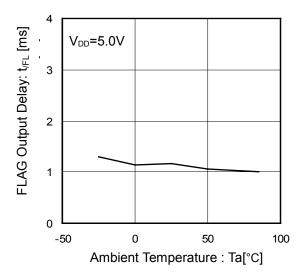


Figure 26. FLAG Output Delay vs Ambient Temperature

BD2042AFJ/BD2052AFJ

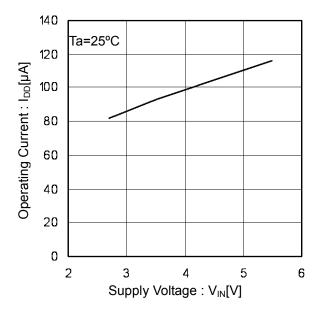


Figure 27. Operating Current vs Supply Voltage (EN, /EN Enable)

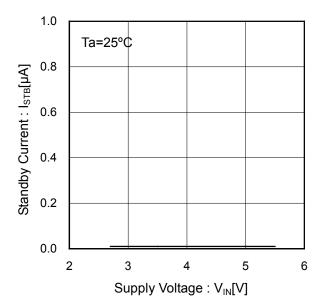


Figure 29. Standby Current vs Supply Voltage (EN, /EN Disable)

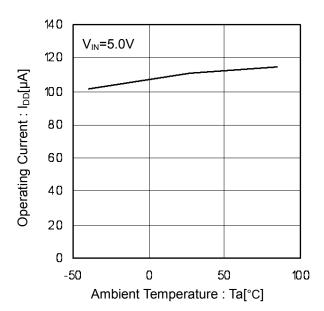


Figure 28. Operating Current vs Ambient Temperature (EN, /EN Enable)

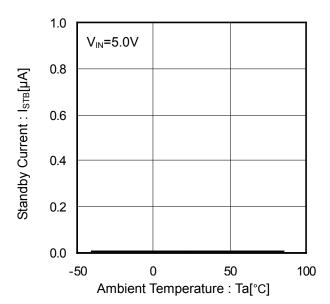


Figure 30. Standby Current vs Ambient Temperature (EN, /EN Disable)

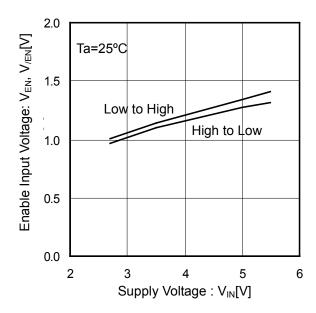


Figure 31. EN, /EN Input Voltage vs Supply Voltage

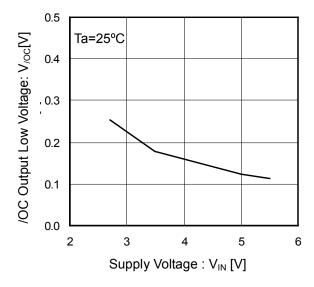


Figure 33. /OC Output Low Voltage vs Supply Voltage

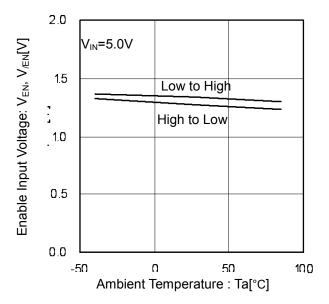


Figure 32. EN, /EN Input Voltage vs Ambient Temperature

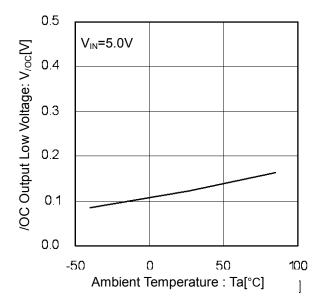


Figure 34. /OC Output Low Voltage vs Ambient Temperature

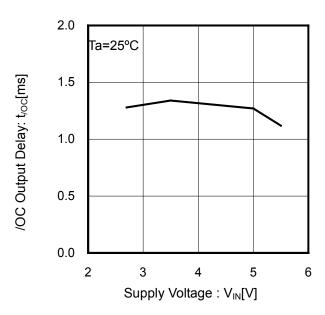


Figure 35. /OC Output Delay vs Supply Voltage

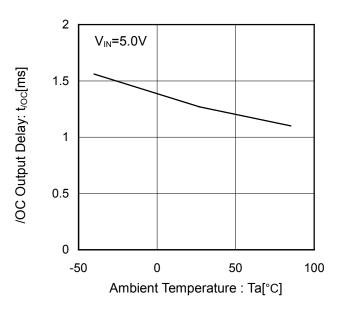


Figure 36. /OC Output Delay vs Ambient Temperature

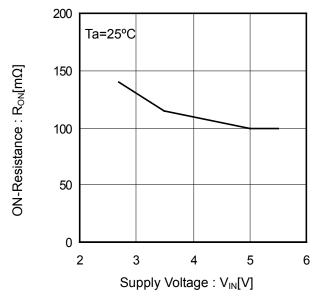


Figure 37. ON-Resistance vs Supply Voltage

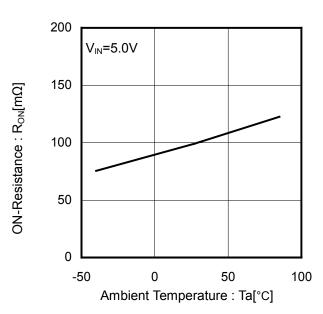


Figure 38. ON-Resistance vs Ambient Temperature

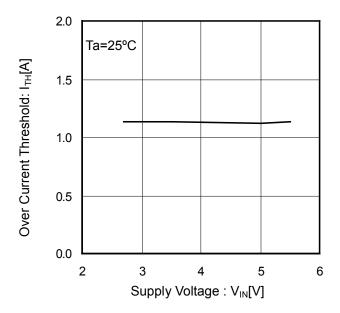


Figure 39. Over Current Threshold vs Supply Voltage

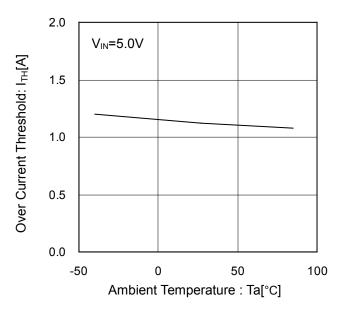


Figure 40. Over Current Threshold vs Ambient Temperature

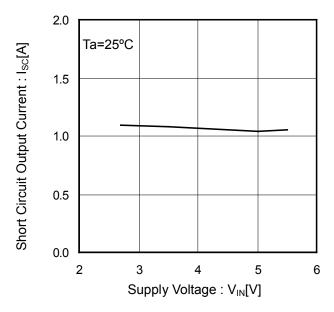


Figure 41. Short Circuit Output Current vs Supply Voltage

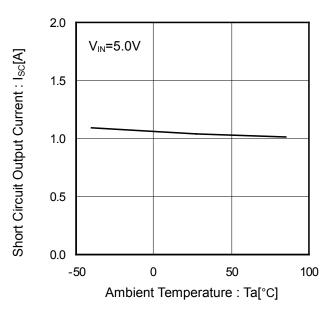


Figure 42. Short Circuit Output Current vs Ambient Temperature

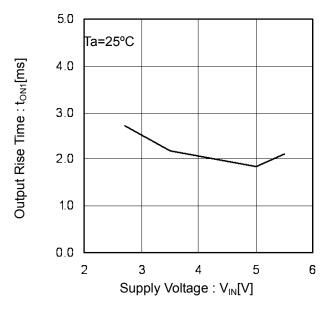


Figure 43. Output Rise Time vs Supply Voltage

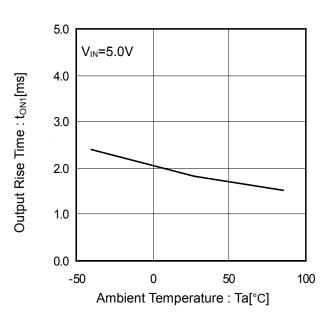


Figure 44. Output Rise Time vs Ambient Temperature

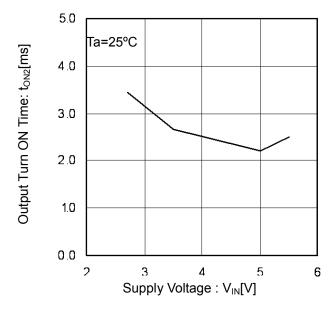


Figure 45. Output Turn ON Time vs Supply Voltage

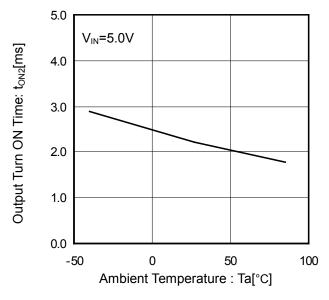


Figure 46. Output Turn ON Time vs Ambient Temperature

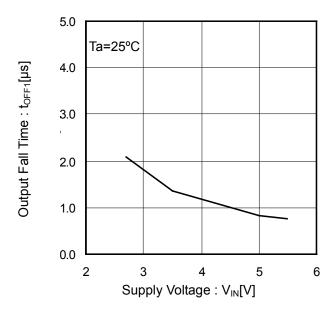


Figure 47. Output Fall Time vs Supply Voltage

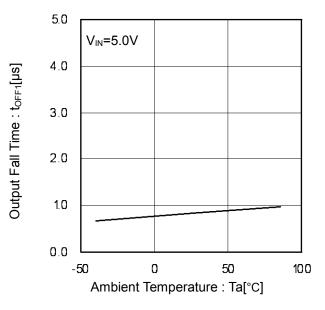


Figure 48. Output Fall Time vs Ambient Temperature

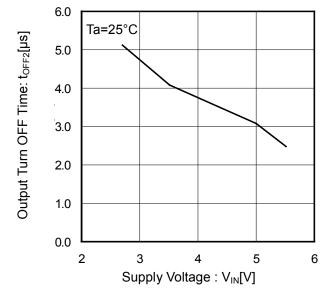


Figure 49. Output Turn OFF Time vs Supply Voltage

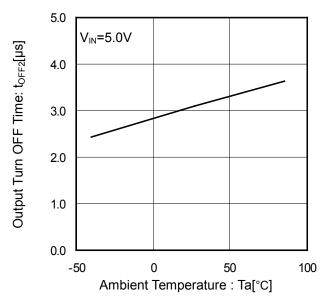


Figure 50. Output Turn OFF Time vs Ambient Temperature

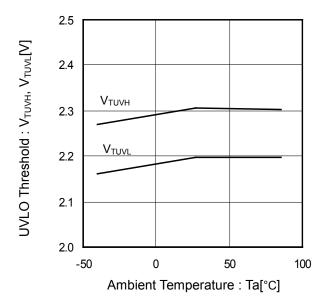


Figure 51. UVLO Threshold Voltage vs Ambient Temperature

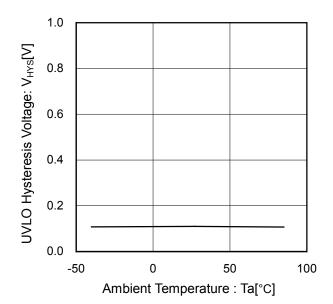


Figure 52. UVLO Hysteresis Voltage vs Ambient Temperature

### **Typical Wave Forms**

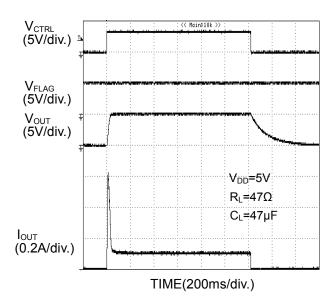


Figure 53. Output Rise / Fall Characteristic (BD6516F)

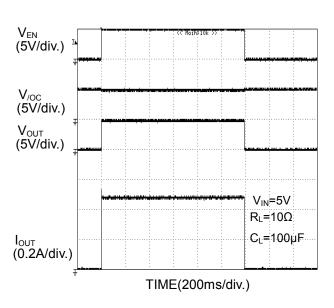


Figure 54. Output Rise / Fall Characteristic (BD2052AFJ)

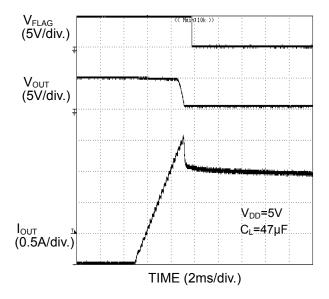


Figure 55. Over-Current Response Ramped Load (BD6516F)

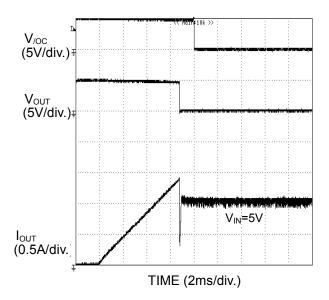


Figure 56. Over-Current Response Ramped Load (BD2052AFJ)

### **Typical Wave Forms - continued**

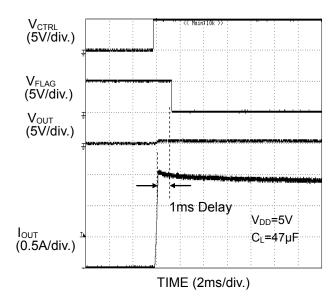


Figure 57. Over-Current Response Enable to Short Circuit (BD6516F)

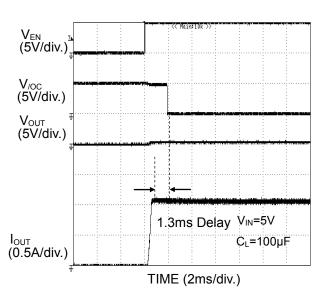


Figure 58. Over-Current Response Enable to 1Ω Short Circuit (BD2052AFJ)

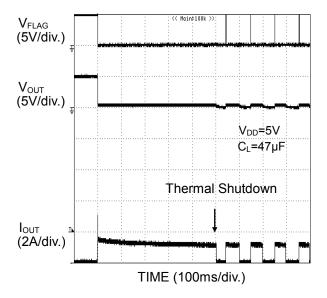


Figure 59. Over-Current Response  $1\Omega$  Load Connected at Enable (BD6516F)

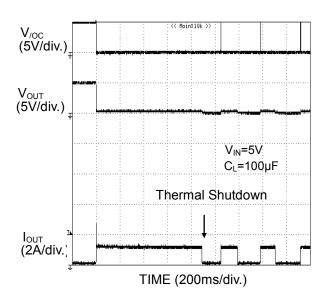
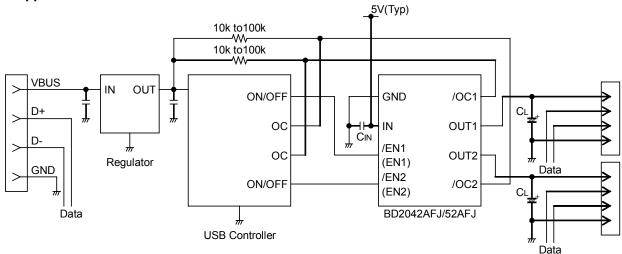


Figure 60. Over-Current Response  $1\Omega$  Load Connected at Enable (BD2052AFJ)

Regarding the output rise/fall and over current detection characteristics of BD6517F, BD2042AFJ refer to the characteristic of BD6516F, BD2052AFJ.

### **Typical Application Circuit**



### **Application Information**

Excessive current flow due to output short circuit, or so, may induce ringing because of the presence of an inductance between the supply line and IC. This event may cause IC malfunction during operation. To avoid this, connect a bypass capacitor between IN and GND pins.  $1\mu$ F or higher is recommended.

Pull up flag output (/OC) by resistance value from  $10k\Omega$  to  $100k\Omega$ .

Set up values of C<sub>L</sub> which satisfies the application.

The application circuit above does not guarantee its operation.

When using the circuit with changes to the external circuit constants, make sure to leave an adequate margin for external components including AC/DC characteristics as well as IC transient characteristics.

### **Functional Description**

### 1. Switch Operation

VDD(IN) pin and OUT pin are connected to the drain and the source of switch MOSFET respectively. The VDD(IN) pin is also used as a power source for internal control circuit.

When the switch is turned on from CTRL(EN) control input, VDD(IN) and OUT are connected. In a normal condition, current flows from VDD to OUT. If the voltage at OUT is higher than VDD, current flows from OUT to VDD since the There is no parasitic diode and it is possible to prevent current flow from OUT to VDD(IN).

#### 2. Thermal Shutdown (TSD)

Thermal shutdown circuit turns off the switch and outputs an error flag when the junction temperature in the chip exceeds a threshold temperature. The thermal shutdown circuit works when either of the two control signals is active.

In BD6516F/BD6517F, the switches of both OUTA and OUTB turn off and output error flags;. BD2042AFJ/ BD2052AFJ has dual threshold temperature for its thermal shutdown. Since thermal shutdown works at a lower junction temperature, only the switch with an over current state turns off whenever over current occurs and outputs an error flag.

Thermal shutdown detection has hysteresis. Therefore, when the junction temperature goes down, switch turns on and error flag is cancelled. Unless the increase of the chip's temperature is removed or the output of power switch is turned off, this operation repeats.

#### 3. Over-Current Detection/Limit Circuit

The over current detection circuit limits current ( $I_{SC}$ ) and outputs an error flag (/OC) when current flowing in each switch MOSFET exceeds a specified value. There are three types of response against over current. The over current detection circuit works when the switch is on (CTRL, EN signal is active).

- (1) When the switch is turned on while the output is in short-circuit status, the switch goes into current limit status immediately.
- (2) When the output short-circuits or high-current load is connected while the switch is on, very large current flows until the over current limit circuit reacts. When the current detection and limit circuit works, current limitation is carried out.
- (3) When the output current increases gradually, current limitation does not work until the output current exceeds the over current detection value. When it exceeds the detection value, current limitation is carried out.

#### 4. Under Voltage Lockout (UVLO)

UVLO circuit turns off the switch to prevent malfunction when the supply voltage is below the UVLO threshold level, The UVLO circuit works when either of two control signals is active.

#### ©BD2042AFJ/BD2052AFJ

UVLO circuit prevents the switch from turning on until the  $V_{IN}$  exceeds 2.3V(Typ). If the  $V_{IN}$  drops below 2.2V(Typ) while the switch is ON, then UVLO shuts OFF the switch. UVLO has hysteresis of 100mV(Typ).

#### 5. Error Flag (/OC) Output

Error flag output is an N-MOS open drain output.

At detection of over current limit and thermal shutdown, /OC outputs a low level signal. Error flag output (/OC) at over current detection has a delay filter. This delay filter prevents instantaneous current detection such as inrush current at switch ON, or applying external power supplies. If fault flag output is unused, /OC pin should be connected to open or ground line.

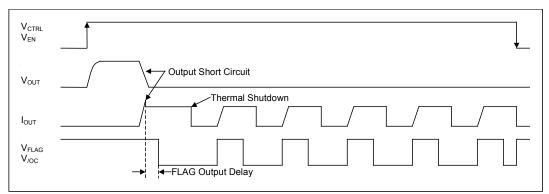
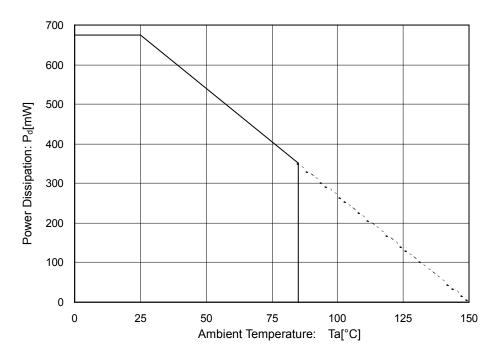


Figure 61. BD6516F/ BD6517F/BD2042AFJ/ BD2052AFJ Over Current Detection, Thermal Shutdown Timing Diagram (V<sub>CTRL</sub>, V<sub>/EN</sub> of BD6517F/BD2042AFJ Active Low)

### **Power Dissipation**

(SOP8, SOP-J8)



70mm x 70mm x 1.6mm Glass Epoxy Board

Figure 62. Power Dissipation Curve

### I/O Equivalence Circuit

### BD6516F/BD6517F

Symbol	Pin No.	Equivalence Circuit
CTRLA CTRLB	1, 4	CTRLA CTRLB
FLAGA FLAGB	2, 3	FLAGA FLAGB
OUTA OUTB	5, 8	OUTA OUTB

### BD2042AFJ/BD2052AFJ

DDZU4ZAFJ/DDZU	JUZ/ (I U	
Symbol	Pin No	Equivalence Circuit
/EN1(EN1) /EN2(EN2)	3, 4	/EN1(EN1) /EN2(EN2)
/OC1 /OC2	5, 8	/OC1 /OC2
OUT1 OUT2	6, 7	OUT1 OUT2

#### **Operational Notes**

#### 1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

#### 2. Power Supply Lines

Design the PCB layout pattern to provide low impedance supply lines. Separate the ground and supply lines of the digital and analog blocks to prevent noise in the ground and supply lines of the digital block from affecting the analog block. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

#### 3. Ground Voltage

Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

### 4. Ground Wiring Pattern

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

#### 5. Thermal Consideration

Should by any chance the power dissipation rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. The absolute maximum rating of the Pd stated in this specification is when the IC is mounted on a 70mm x 70mm x 1.6mm glass epoxy board. In case of exceeding this absolute maximum rating, increase the board size and copper area to prevent exceeding the Pd rating.

#### 6. Recommended Operating Conditions

These conditions represent a range within which the expected characteristics of the IC can be approximately obtained. The electrical characteristics are guaranteed under the conditions of each parameter.

#### 7. In rush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

#### 8. Operation Under Strong Electromagnetic Field

Operating the IC in the presence of a strong electromagnetic field may cause the IC to malfunction.

### 9. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

### 10. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

### **Operational Notes - continued**

#### 11. Unused Input Pins

Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

#### 12. Regarding the Input Pin of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode. When GND > Pin B, the P-N junction operates as a parasitic transistor.

Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.

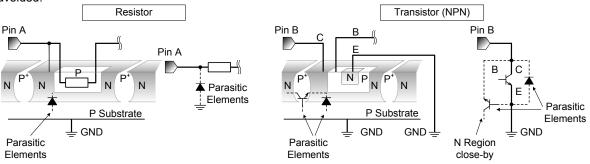


Figure 63. Example of monolithic IC structure

#### 13. Ceramic Capacitor

When using a ceramic capacitor, determine the dielectric constant considering the change of capacitance with temperature and the decrease in nominal capacitance due to DC bias and others.

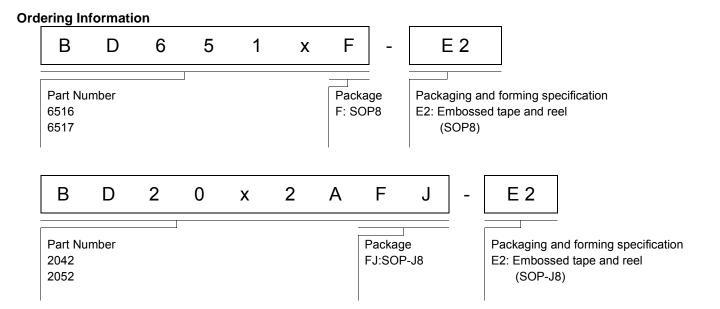
### 14. Thermal Shutdown Circuit(TSD)

This IC has a built-in thermal shutdown circuit that prevents heat damage to the IC. Normal operation should always be within the IC's power dissipation rating. If however the rating is exceeded for a continued period, the junction temperature (Tj) will rise which will activate the TSD circuit that will turn OFF all output pins. When the Tj falls below the TSD threshold, the circuits are automatically restored to normal operation.

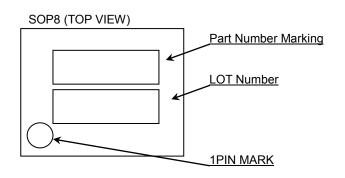
Note that the TSD circuit operates in a situation that exceeds the absolute maximum ratings and therefore, under no circumstances, should the TSD circuit be used in a set design or for any purpose other than protecting the IC from heat damage.

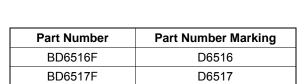
#### 15. Thermal design

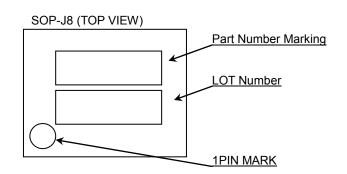
Perform thermal design in which there are adequate margins by taking into account the power dissipation (Pd) in actual states of use.



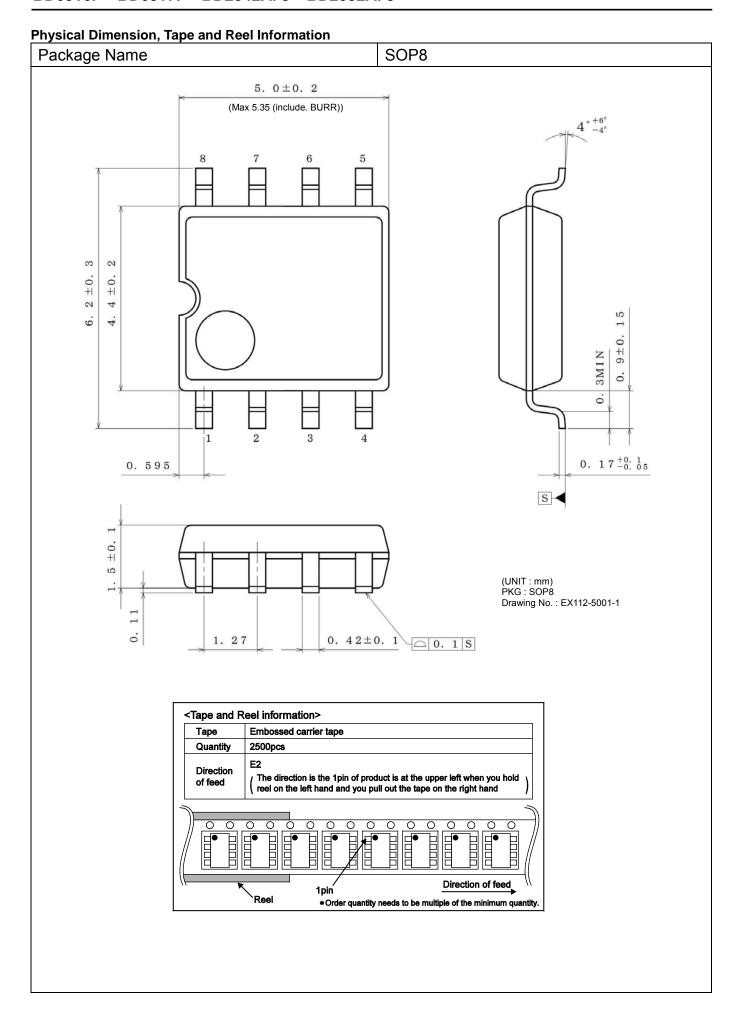
### **Marking Diagrams**

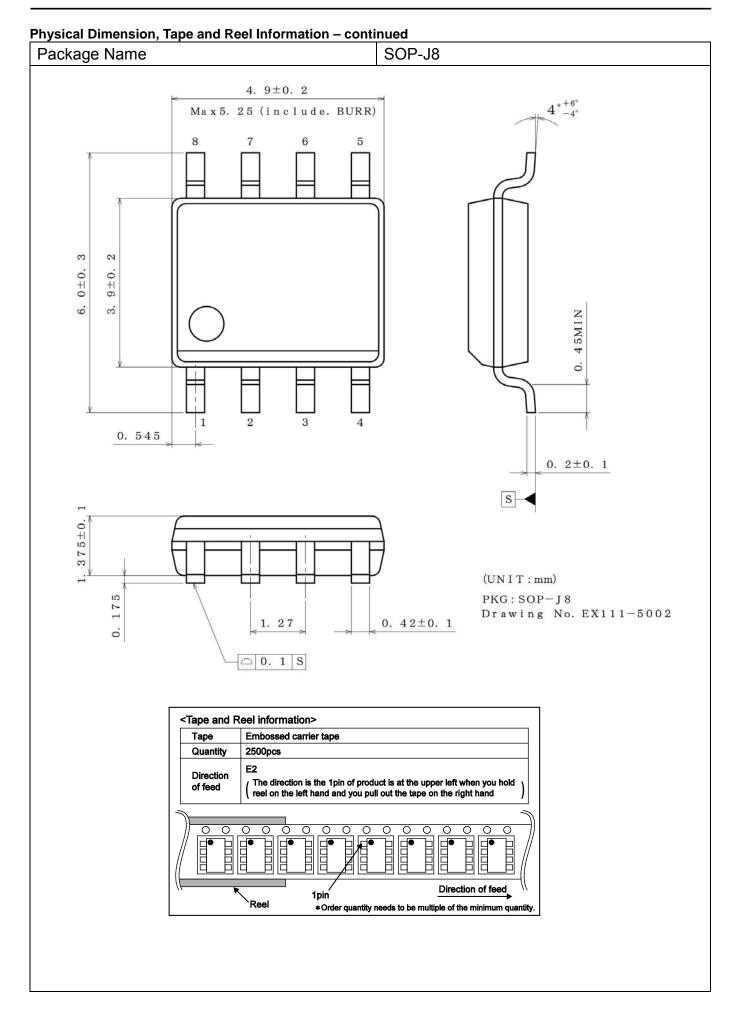






Part Number Marking
D042A
D052A





### **Revision History**

Date	Revision	Changes		
11.Mar.2013	001	New Release		
25.Jun.2013	002	Changed character color from RED to BLACK on page 6.		
21.Aug.2014	003	Applied the ROHM Standard Style and improved understandability. Delete BD6512F and BD6513F.		

## **Notice**

### **Precaution on using ROHM Products**

Our Products are designed and manufactured for application in ordinary electronic equipments (such as AV equipment, OA equipment, telecommunication equipment, home electronic appliances, amusement equipment, etc.). If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment (Note 1), transport equipment, traffic equipment, aircraft/spacecraft, nuclear power controllers, fuel controllers, car equipment including car accessories, safety devices, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

(Note1) Medical Equipment Classification of the Specific Applications

JAPAN	USA	EU	CHINA
CLASSⅢ	CL A C C TT	CLASS II b	CLASSIII
CLASSIV	CLASSIV CLASSIII		CLASSIII

- 2. ROHM designs and manufactures its Products subject to strict quality control system. However, semiconductor products can fail or malfunction at a certain rate. Please be sure to implement, at your own responsibilities, adequate safety measures including but not limited to fail-safe design against the physical injury, damage to any property, which a failure or malfunction of our Products may cause. The following are examples of safety measures:
  - [a] Installation of protection circuits or other protective devices to improve system safety
  - [b] Installation of redundant circuits to reduce the impact of single or multiple circuit failure
- 3. Our Products are designed and manufactured for use under standard conditions and not under any special or extraordinary environments or conditions, as exemplified below. Accordingly, ROHM shall not be in any way responsible or liable for any damages, expenses or losses arising from the use of any ROHM's Products under any special or extraordinary environments or conditions. If you intend to use our Products under any special or extraordinary environments or conditions (as exemplified below), your independent verification and confirmation of product performance, reliability, etc, prior to use, must be necessary:
  - [a] Use of our Products in any types of liquid, including water, oils, chemicals, and organic solvents
  - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
  - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
  - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
  - [f] Sealing or coating our Products with resin or other coating materials
  - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
  - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation (Pd) depending on Ambient temperature (Ta). When used in sealed area, confirm the actual ambient temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

#### Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used; if flow soldering method is preferred, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

### **Precautions Regarding Application Examples and External Circuits**

- If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
- You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

#### **Precaution for Electrostatic**

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of Ionizer, friction prevention and temperature / humidity control).

### **Precaution for Storage / Transportation**

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
  - [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
  - [b] the temperature or humidity exceeds those recommended by ROHM
  - the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

#### Precaution for Product Label

QR code printed on ROHM Products label is for ROHM's internal use only.

#### **Precaution for Disposition**

When disposing Products please dispose them properly using an authorized industry waste company.

#### **Precaution for Foreign Exchange and Foreign Trade act**

Since our Products might fall under controlled goods prescribed by the applicable foreign exchange and foreign trade act, please consult with ROHM representative in case of export.

#### **Precaution Regarding Intellectual Property Rights**

- 1. All information and data including but not limited to application example contained in this document is for reference only. ROHM does not warrant that foregoing information or data will not infringe any intellectual property rights or any other rights of any third party regarding such information or data. ROHM shall not be in any way responsible or liable for infringement of any intellectual property rights or other damages arising from use of such information or data.:
- 2. No license, expressly or implied, is granted hereby under any intellectual property rights or other rights of ROHM or any third parties with respect to the information contained in this document.

### **Other Precaution**

- 1. This document may not be reprinted or reproduced, in whole or in part, without prior written consent of ROHM.
- 2. The Products may not be disassembled, converted, modified, reproduced or otherwise changed without prior written consent of ROHM.
- 3. In no event shall you use in any way whatsoever the Products and the related technical information contained in the Products or this document for any military purposes, including but not limited to, the development of mass-destruction weapons.
- The proper names of companies or products described in this document are trademarks or registered trademarks of ROHM, its affiliated companies or third parties.

#### **General Precaution**

- 1. Before you use our Products, you are requested to care fully read this document and fully understand its contents. ROHM shall not be in an y way responsible or liable for failure, malfunction or accident arising from the use of a ny ROHM's Products against warning, caution or note contained in this document.
- 2. All information contained in this docume nt is current as of the issuing date and subject to change without any prior notice. Before purchasing or using ROHM's Products, please confirm the latest information with a ROHM sale s representative.
- 3. The information contained in this doc ument is provided on an "as is" basis and ROHM does not warrant that all information contained in this document is accurate an d/or error-free. ROHM shall not be in an y way responsible or liable for any damages, expenses or losses incurred by you or third parties resulting from inaccuracy or errors of or concerning such information.

**Notice – WE** © 2014 ROHM Co., Ltd. All rights reserved. Rev.001

# **Mouser Electronics**

**Authorized Distributor** 

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

ROHM Semiconductor: BD6516F-E2